

03599.000081



PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:	)	
SHINZO UCHIYAMA	)	Examiner: Not Yet Assigned
Application No.: 10/699883	)	Group Art Unit: NYA
Filed: November 4, 2003	)	
For: PROCESS FOR PRODUCING	)	
A SEMICONDUCTOR	)	
DEVICE	)	January 6, 2004

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

In compliance with the duty of disclosure under 37 C.F.R. § 1.56 and in accordance with the practice under 37 C.F.R. §§ 1.97 and 1.98, the Examiner's attention is directed to the documents listed on the enclosed Form PTO-1449. Copies of the listed foreign documents are also enclosed.

The concise explanation of relevance for the non-English documents is found in the specification where cited, in a corresponding U.S. Patent No. 6,497,783 for JPLO 2925535 and in translations of Preprints for Japan Soc. of Appl. Physics.

CONCLUSION

It is respectfully requested that the above information be considered by the Examiner and that a copy of the enclosed Form PTO-1449 be returned indicating that such information has been considered.

Applicant's undersigned attorney may be reached in our New York office by telephone at (212) 218-2100. All correspondence should continue to be directed to our address given below.

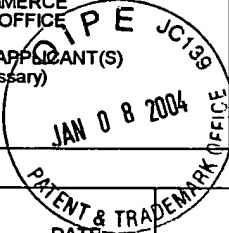
Respectfully submitted,



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NY\_MAIN 397360v1

FORM PTO 1449 (modified)  U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE  LIST OF REFERENCES CITED BY APPLICANT(S) (Use several sheets if necessary)				ATTY DOCKET NO. <b>03599.000081</b>		APPLICATION NO. <b>10/699883</b>	
				APPLICANT <b>SHINZO UCHIYAMA</b>			
				FILING DATE <b>November 4, 2003</b>			GROUP <b>UNASSIGNED</b>
U.S. PATENT DOCUMENTS							
*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
		5753320	5/98	Mikoshiba, et al.	427	572	
		6217704	3/01	Kitagawa	156	345	
		6410450	6/02	Kitagawa	438	710	
		6426302	7/02	Kitigawa	438	710	
		6497783	12/02	Suzuki, et al.	156	345	5/98
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION YES/NO/ OR ABSTRACT
	JP	2925535	5/99	JAPAN			
OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)							
		Sasada, et al.; "Low Temperature Formation .... Activated Oxygen/Nitrogen"; 62nd Japan Soc. Appl. Phys., Annual Meeting Preprint No. 2, page 631, 12a-C-10 (2001)					
		Aria, et al.; "The origin of the increase .... silicon oxide"; 62nd Japan Soc. Appl. Phys., Annual Meeting Preprint No. 2, page 630, 12a-C-9 (2001)					
EXAMINER				DATE CONSIDERED			

\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.